

Transistors

4V Drive Pch MOSFET

RSR020P03

●Structure

Silicon P-channel MOSFET

●Features

- 1) Low On-resistance
- 2) Space saving—small surface mount package (TSMT3)
- 3) 4V drive

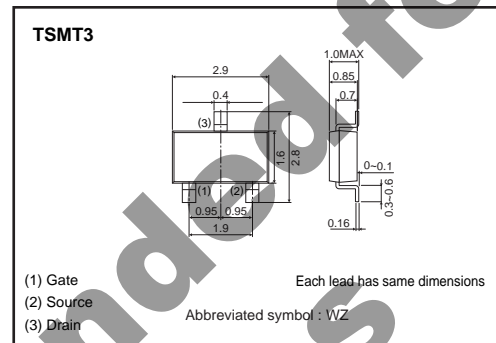
●Applications

Switching

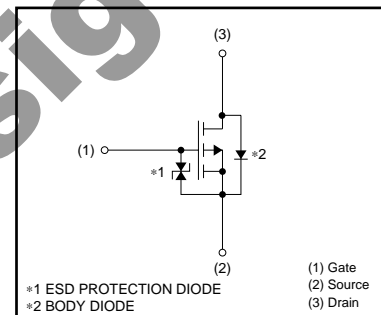
●Packaging specifications

Type	Package	Taping
	Code	TL
	Basic ordering unit (pieces)	3000
RSR020P03		○

●Dimensions (Unit : mm)



●Inner circuit



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Drain-source voltage	V_{DS}	-30	V	
Gate-source voltage	V_{GS}	±20	V	
Drain current	Continuous	I_D	±2	A
	Pulsed	I_{DP} *1	±8	A
Source current (Body diode)	Continuous	I_S	-0.8	A
	Pulsed	I_{SP} *1	-8	A
Total power dissipation	P_D *2	1	W	
Channel temperature	T_{ch}	150	°C	
Range of storage temperature	T_{stg}	-55 to +150	°C	

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

*2 Mounted on a ceramic board

●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}$ *	125	°C/W

* Mounted on a ceramic board

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●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I _{GSS}	–	–	±10	μA	V _{GS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V _{(BR) DSS}	–30	–	–	V	I _D = –1mA, V _{GS} =0V
Zero gate voltage drain current	I _{DSS}	–	–	–1	μA	V _{DS} = –30V, V _{GS} =0V
Gate threshold voltage	V _{GS(th)}	–1.0	–	–2.5	V	V _{DS} = –10V, I _D = –1mA
Static drain-source on-state resistance	R _{DS(on)} *	–	85	120	mΩ	I _D = –2A, V _{GS} = –10V
		–	135	190	mΩ	I _D = –1A, V _{GS} = –4.5V
		–	150	210	mΩ	I _D = –1A, V _{GS} = –4V
Forward transfer admittance	Y _{fs} *	1.4	–	–	S	V _{DS} = –10V, I _D = –1A
Input capacitance	C _{iss}	–	370	–	pF	V _{DS} = –10V
Output capacitance	C _{oss}	–	80	–	pF	V _{GS} =0V
Reverse transfer capacitance	C _{rss}	–	55	–	pF	f=1MHz
Turn-on delay time	t _{d(on)} *	–	8	–	ns	V _{DD} ≐ –15V
Rise time	t _r *	–	10	–	ns	I _D = –1A
Turn-off delay time	t _{d(off)} *	–	35	–	ns	V _{GS} = –10V
Fall time	t _f *	–	11	–	ns	R _L =15Ω R _G =10Ω
Total gate charge	Q _g *	–	4.3	–	nC	V _{DD} ≐ –15V V _{GS} = –5V
Gate-source charge	Q _{gs} *	–	1.4	–	nC	I _D = –2A
Gate-drain charge	Q _{gd} *	–	1.5	–	nC	R _L =7.5Ω R _G =10Ω

*Pulsed

●Body diode characteristics (Source-drain) (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V _{SD} *	–	–	–1.2	V	I _S = –0.8A, V _{GS} =0V

*Pulsed

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●Electrical characteristics curves

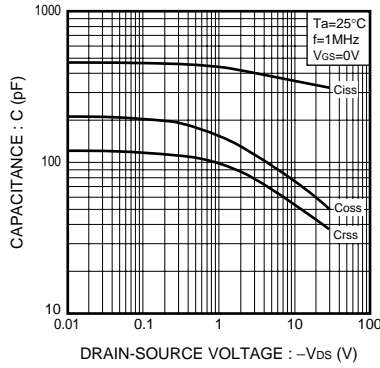


Fig.1 Typical Capacitance vs. Drain-Source Voltage

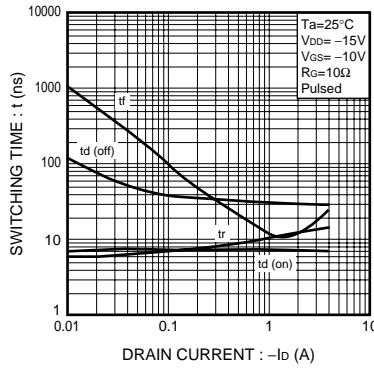


Fig.2 Switching Characteristics

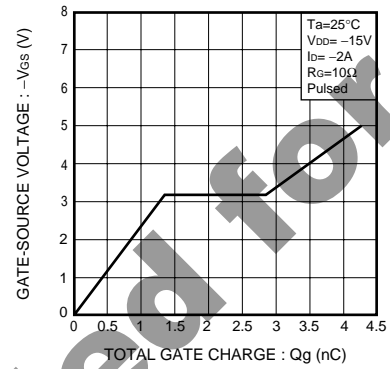


Fig.3 Dynamic Input Characteristics

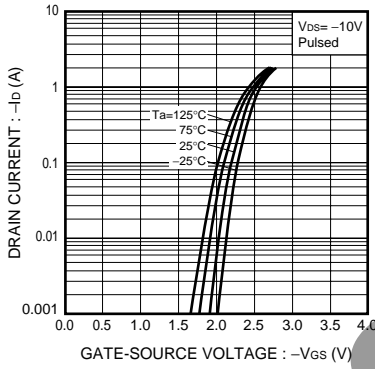


Fig.4 Typical Transfer Characteristics

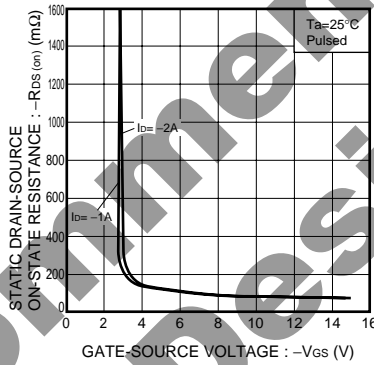


Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

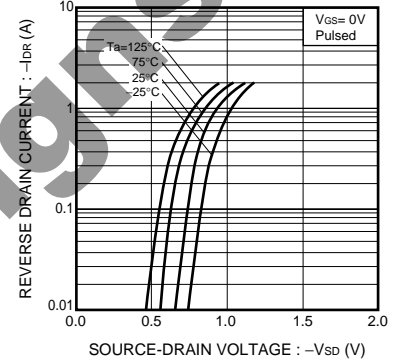


Fig.6 Reverse Drain Current vs. Source-Drain Voltage

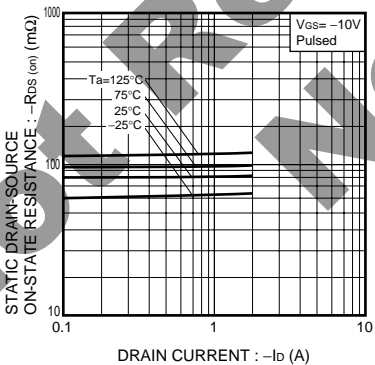


Fig.7 Static Drain-Source On-State Resistance vs. Drain current (I)

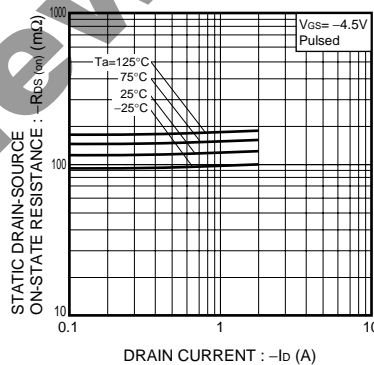


Fig.8 Static Drain-Source On-State Resistance vs. Drain current (II)

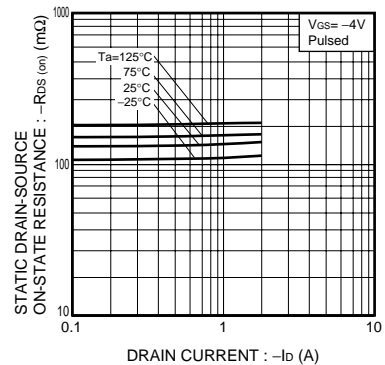


Fig.9 Static Drain-Source On-State Resistance vs. Drain current (III)

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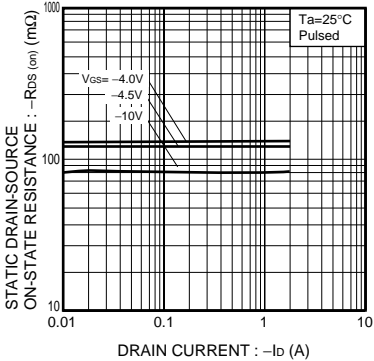


Fig.10 Static Drain-Source On-State Resistance vs. Drain current (IV)

Not Recommended for New Designs

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